

YJ Planar Schottky Barrier Diode Die Specification

150V 20A, 120mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB120H150SS-280A

Main Products Characteristics

- Average forward current: $I_F(AV) = 20\text{ A}$
- Maximum operating junction temperature: $T_j = 175^\circ\text{C}$
- ESD rating: >2KV, per IEC61000-4-2 (Contact Discharge)